



**THE DATASHEET OF  
SI8932D-IS4**





## DATA SHEET

# Si8931 and Si8932 Isolated Analog Amplifier

## Applications

- Industrial, HEV and renewable energy inverters
- AC, brushless, and DC motor controls and drives
- Variable speed motor control in white goods
- Isolated switch mode and UPS power supplies
- General industrial data acquisition and sensor interface
- Automotive on-board chargers, battery management systems, and charging stations

## Features

- 0 to 2.5 V nominal input voltage
- Low signal delay: 1  $\mu$ s
- Typical input offset: 0.16 mV
- Typical gain error:  $\pm$ 0.06%
- Excellent drift specifications
  - 0.75  $\mu$ V/ $^{\circ}$ C offset drift
  - 6 ppm/ $^{\circ}$ C typical gain drift
- Typical nonlinearity: 0.01%
- Typical SNR: 76 dB
- High common-mode transient immunity: 75 kV/ $\mu$ s
- Automotive-grade OPNs available
  - AEC-Q100 qualification
  - AIAG-compliant PPAP documentation support
  - IMDS and CAMDS listing support
- Compact packages
  - 8-pin wide body stretched SOIC
  - 8-pin narrow body SOIC
- -40 to 125  $^{\circ}$ C

## Safety Approvals

- UL 1577 recognized
  - Up to 5000 kV<sub>RMS</sub> for 1 minute
- CSA certification conformity
  - 62368-1 (reinforced insulation)
- VDE certification conformity (pending)
  - 60747-17 (reinforced insulation)
- CQC certification approval
  - GB4943.1

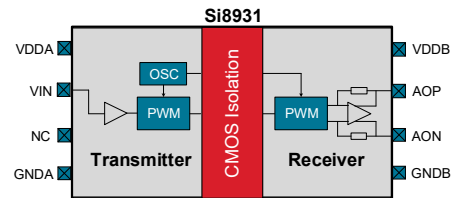


Figure 1. Si8931 Block Diagram

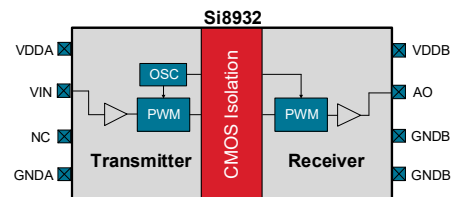


Figure 2. Si8932 Block Diagram

## Description

The Si8931 and Si8932 galvanically isolated analog amplifiers feature 2.5 V input range and are optimized for isolated voltage sensing applications. The output is a differential analog signal (Si8931) or a single-ended signal (Si8932) proportional to the input voltage.

The Si8931/32 provide excellent linearity with low offset and gain drift to maintain accuracy over the entire operating temperature range. Exceptionally high common-mode transient immunity ensures the Si8931/32 deliver accurate measurements even in the presence of high-power switching in motor drive systems and inverters.

The Si8931/32 isolated voltage sensing amplifier utilizes Skyworks proprietary isolation technology, and withstands up to 5.0 kV<sub>RMS</sub> per UL1577. This technology enables high performance, reduced variation with temperature and age, tighter part-to-part matching, and longer lifetimes compared to other isolation technologies.

Automotive Grade is available for certain part numbers. These products are built using automotive-specific flows at all steps in the manufacturing process to ensure the robustness and low defectivity required for automotive applications.



Skyworks Green™ products are compliant with all applicable legislation and are halogen-free. For additional information, refer to *Skyworks Definition of Green™*, document number SQ04-0074.

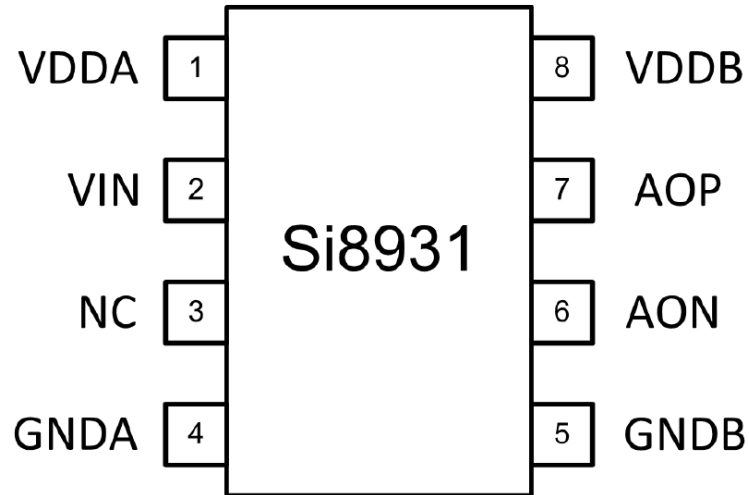


Figure 3. Si8931 Pinout (Top View)

Table 1. Si8931 Pin Descriptions

Name	Pin Number	Description
VDDA	1	Input side power supply
VIN	2	Voltage input
NC <sup>1</sup>	3	No Connect
GNDA	4	Input side ground
GNDB	5	Output side ground
AON	6	Analog output low
AOP	7	Analog output high
VDDB	8	Output side power supply

1. No Connect. These pins are not internally connected. To maximize CMTI performance, these pins should be connected to the ground plane.

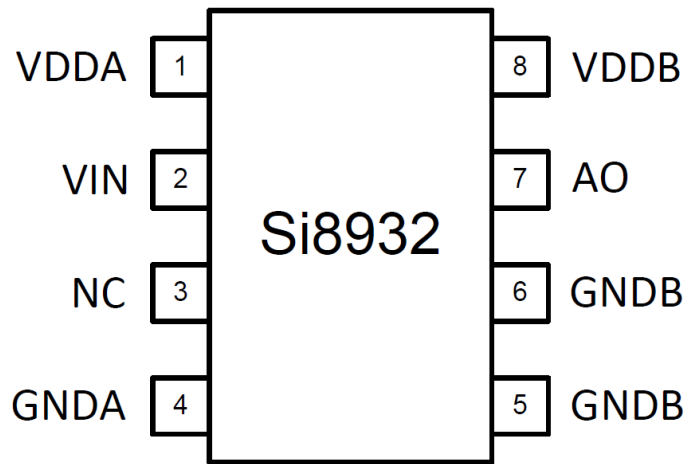


Figure 4. Si8932 Pinout (Top View)

Table 2. Si8932 Pin Descriptions

Name	Pin Number	Description
VDDA	1	Input side power supply
VIN	2	Voltage input
NC <sup>1</sup>	3	No Connect
GNDA	4	Input side ground
GNDB <sup>2</sup>	5	Output side ground
GNDB <sup>2</sup>	6	Output side ground
AO	7	Analog output
VDDB	8	Output side power supply

1. No Connect. These pins are not internally connected. To maximize CMTI performance, these pins should be connected to the ground plane.
2. Both pin 5 and pin 6 must be connected to ground.

## 1. Technical Description

The Si8931/32 are designed for 0 to 2.5 V nominal input.

The Si8931/32 modulates the analog signal in a unique way for transmission across the semiconductor based isolation barrier. The input signal is first converted to a pulse-width modulated digital signal. On the other side of the isolation barrier, the signal is demodulated to faithfully reproduce the analog signal. This solution provides exceptional signal bandwidth and accuracy. The Si8931 provides a differential voltage output while the Si8932 provides a single-ended voltage output.

### 1.1. Fail-Safe and Low-Power Modes

The Si8931/32 implements a fail-safe output when the high-side supply voltage VDDA goes away. This is important for safe operation in systems with high safety requirements. The fail-safe output is nominally 2.8 V (Si8932) or –2.8 V (Si8931) which can be differentiated from the maximum clipping output voltage of 2.6 V to simplify diagnostics on the system level.

**Table 3. Si8931 and Si8932 Output Voltages**

Device	Output Voltage (VDDA Normal)	Output Voltage (VDDA Removed)
Si8931	~ ±2.6 V	~ –2.8 V
Si8932	0 to ~2.6 V	~ +2.8 V

In addition to the fail-safe output, when a loss of VDDA supply occurs, the part will automatically move into a lower power mode that reduces IDDB current to approximately 1 mA. The controller side continues to monitor high-side communications to determine when VDDA supply returns. When the supply voltage is returned, normal operation begins in approximately 250 μs. Similarly, a loss of VDDB supply will reduce IDDA current to approximately 1 mA.

### 1.2. Voltage Sense Application

A typical isolated voltage sensing application circuit is shown below. In this example, a high voltage is divided down to produce a voltage (VIN) within the optimum input signal range of the Si8931/32. Numerous alternative inputs configurations are possible with the flexibility of a high impedance input isolator. The Si8931 senses the single-ended input voltage and reproduces it as a differential (or single-ended with the Si8932) output voltage across the galvanic isolation barrier. The Si8931 differential outputs (AOP, AON) can be routed directly to a differential ADC as shown below. The Si8932 senses the single-ended input voltage and reproduces it as a single-ended output voltage across the galvanic isolation barrier. The single-ended output can be routed directly to a standard ADC (not shown). If the voltage sensed is > 2.5 V, a simple voltage divider consisting of R1 and R2 can be used to scale down any voltage to fit the input range of the Si8931/32. R2 < 10 kΩ is recommended for best performance.

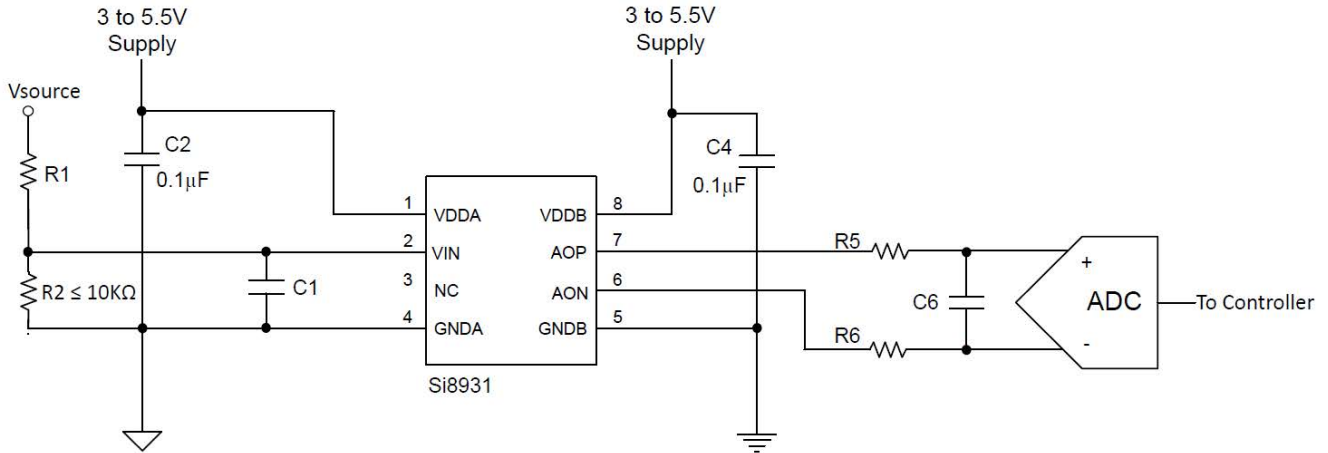


Figure 5. Voltage Sense Application

The amplifier bandwidth of the Si8931/32 is approximately 600 kHz. For applications where input filtering is required, a passive, differential RC low-pass filter can be placed at the input pin. Consider the source resistance of the signal measured (or the parallel combination of R1 and R2 if using a voltage divider) as it should be included in the filter calculation. Capacitor C1 should be sized to make a band limiting filter at the desired frequency.

The local bypass capacitor C4 for the B-side of Si8931/32, should be placed closed to VDDB supply pin with its return close to GNDB. The output signal at AOP and AON is differential with unity gain and common mode of 1.4 V. The outputs are sampled by a differential input ADC. Depending on the sample rate of the ADC, an anti-aliasing filter may be required. A simple anti-aliasing filter can be made from the passive components, R5, C6, and R6. The characteristics of this filter are dictated by the input topology and sampling frequency of the ADC.

However, to ensure the Si8931/32 outputs are not overloaded,  $R5 = R6 > 5 \text{ k}\Omega$  and C6 can be calculated by the following equation:

$$C6 = \frac{1}{2 \times \pi \times (R5 + R6) \times f_{3dB}}$$

## 2. Electrical and Mechanical Specifications

The absolute maximum ratings of the Si8931 and Si8932 are provided below, followed by electrical specifications, performance graphs, and mechanical specifications.

**Table 4. Si8931 and Si8932 Absolute Maximum Ratings<sup>1</sup>**

Parameter	Symbol	Min	Max	Unit
Storage temperature	T <sub>STG</sub>	-65	150	°C
Ambient temperature under bias	T <sub>A</sub>	-40	125	°C
Junction temperature	T <sub>J</sub>		150	°C
Supply voltage	V <sub>DDA</sub> , V <sub>DDDB</sub>	-0.5	6.0	V
Input voltage respect to GNDA	V <sub>IN</sub>	-0.5	V <sub>DDA</sub> + 0.5	V
Output sink or source current	I <sub>o</sub>		5	mA
Total power dissipation	P <sub>T</sub>		212	mW
Lead solder temperature (10 s)			260	°C
Human Body Model ESD rating		6000		V
Charged Device Model ESD rating		2000		V

1. Note: Exposure to maximum rating conditions for extended periods may reduce device reliability. Exceeding any of the limits listed here may result in permanent damage to the device.

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**ESD Handling: Industry-standard ESD handling precautions must be adhered to at all times to avoid damage to this device.**

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Table 5. Si8931 and Si8932 Electrical Specifications<sup>1</sup>

TA = -40 to +125 °C; typical specs at 25 °C with VDDA = VDDB = 5 V unless specified differently under Test Condition							
Parameter	Symbol	Test Condition	Min	Typ	Max	Units	
Input side supply voltage	VDDA		3.0		5.5	V	
Input supply current	Si8931/32	IDDA	VDDA = 3.3 V	4.7	5.7	mA	
Output side supply voltage	VDDB		3.0		5.5	V	
Output supply current	Si8931	IDDB	VDDB = 3.3 V	3.5	4.5	mA	
	Si8932	IDDB	VDDB = 3.3 V	4.3	5	mA	
Amplifier Bandwidth				600		kHz	
<b>Amplifier Input</b>							
Specified linear input range	VIN		0.25		2.25	V	
Maximum input voltage before clipping	VIN			2.5		V	
Input referred offset	VOS	TA = 25 °C, VIN = 0.25 V	-1	±0.16	1	mV	
Input offset drift	VOST		-25	±0.75	25	µV/°C	
Input impedance	RIN			500		MΩ	
<b>Amplifier Output</b>							
Full-scale output				2.5		Vpk	
Gain				1			
Gain error		TA = 25 °C	-0.25	±0.06	0.25	%	
Gain error drift	Si8931		-40	6	20	ppm/°C	
	Si8932		-30	-5	30	ppm/°C	
Output Common Mode Voltage	Si8931	(VAOP + VAON)/2	1.34	1.39	1.44	V	
Nonlinearity	Si8931	TA = 25 °C	-0.04	0.01	0.04	%	
	Si8932	TA = 25 °C	-0.05	0.01	0.05	%	
Nonlinearity drift		TA = 25 °C	-5		5	ppm/°C	
Signal-to-noise ratio	Si8931	SNR	100 kHz bandwidth	73	77	dB	
	Si8932	SNR	100 kHz bandwidth	72	76	dB	
Total harmonic distortion	Si8931	THD	FIN = 1 kHz		-80	-60	dB
	Si8932	THD	FIN = 1 kHz		-80	-60	dB

Table 5. Si8931 and Si8932 Electrical Specifications<sup>1</sup> (Continued)

TA = -40 to +125 °C; typical specs at 25 °C with VDDA = VDDB = 5 V unless specified differently under Test Condition						
Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Power Supply Rejection Ratio	PSRR	VDDA at DC		-100		dB
Power Supply Rejection Ratio	PSRR	VDDA at 100 mV and 10 kHz ripple		-100		dB
		VDDB at DC		-100		dB
		VDDB at 100 mV and 10 kHz ripple		-100		dB
Output Resistive Load	Si8931	RLOAD	Between AON and AOP	5		kΩ
	Si8932		Between AO and GND	5		kΩ
Output capacitive load		CLOAD	Each pin to ground		100	pF
<b>Timing</b>						
Signal delay	t <sub>PD</sub>	50% to 50%		1		μs
Rise time	t <sub>R</sub>	10% to 90%		1.6		μs
Common-mode transient immunity <sup>2</sup>	CMTI	VIN = GNDA, VCM = 1500 V	50	75		kV/μs

1. Performance is guaranteed only under the conditions listed in this Table and is not guaranteed over the full operating or storage temperature ranges. Operation at elevated temperatures may reduce reliability of the device.
2. An analog CMTI failure is defined as an output error of more than 100 mV persisting for at least 1 μs.

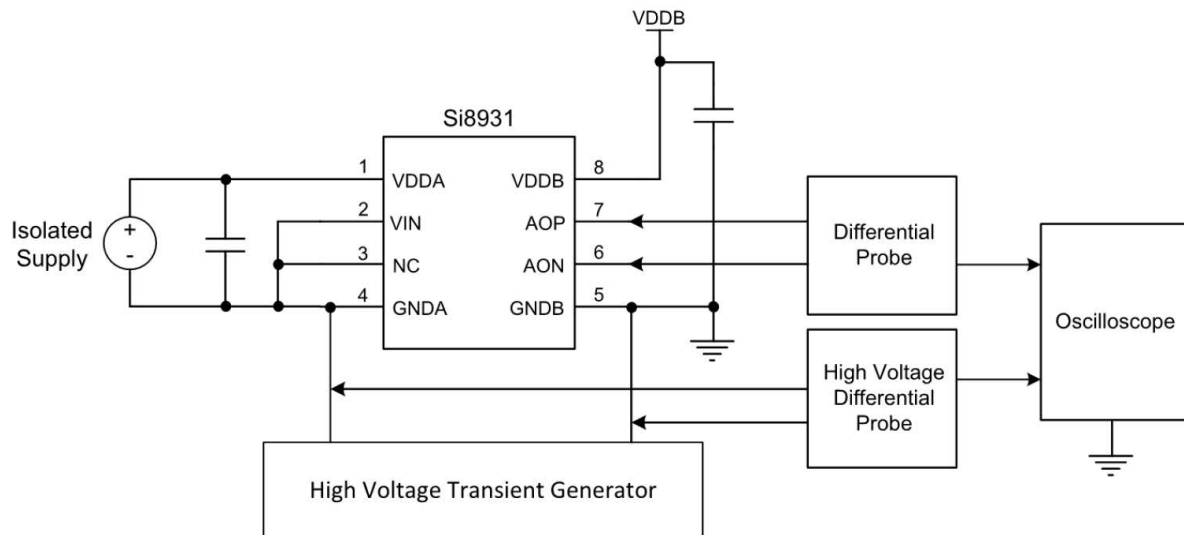


Figure 6. Common-Mode Transient Immunity Characterization Circuit

### 3. Typical Performance Characteristics

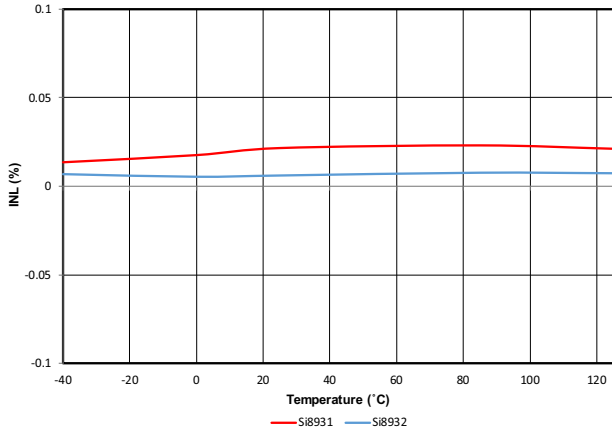


Figure 7. Nonlinearity (%) vs. Temperature (°C)

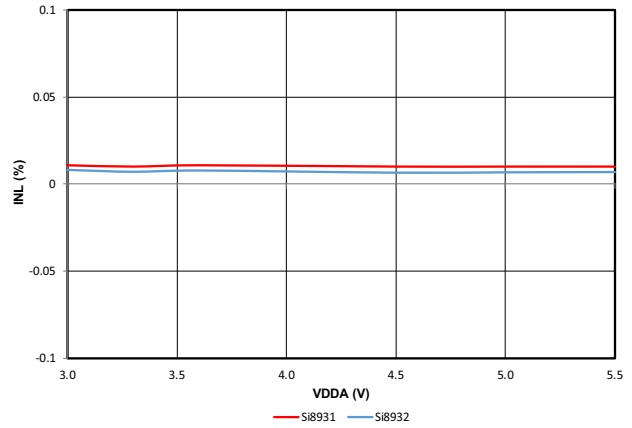


Figure 8. Nonlinearity (%) vs. VDDA Supply (V)

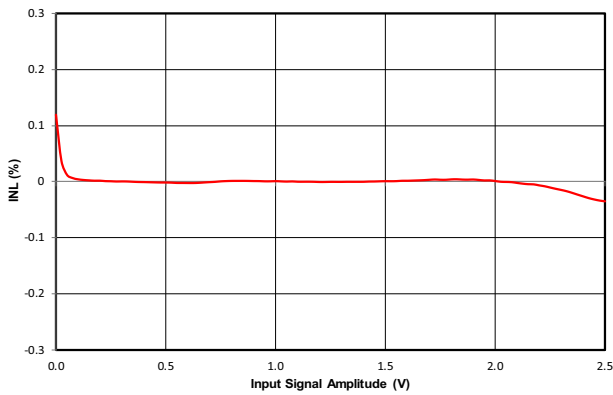


Figure 9. Si8931 Nonlinearity (%) vs. Input Signal Amplitude (mV)

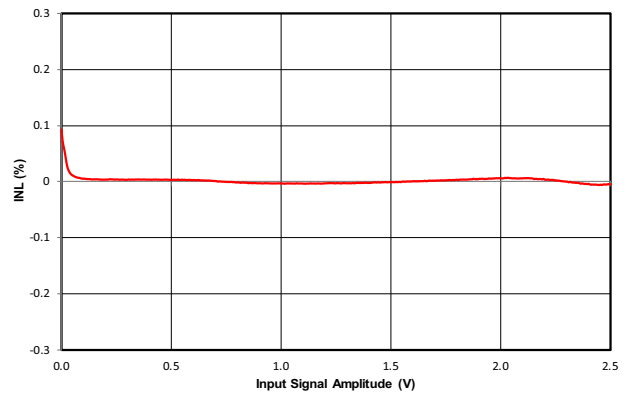


Figure 10. Si8932 Nonlinearity (%) vs. Input Signal Amplitude (mV)

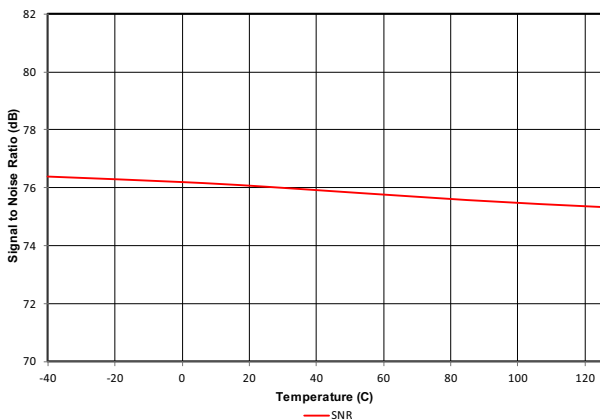


Figure 11. Signal-to-Noise Ratio (dB) vs. Temperature (°C)

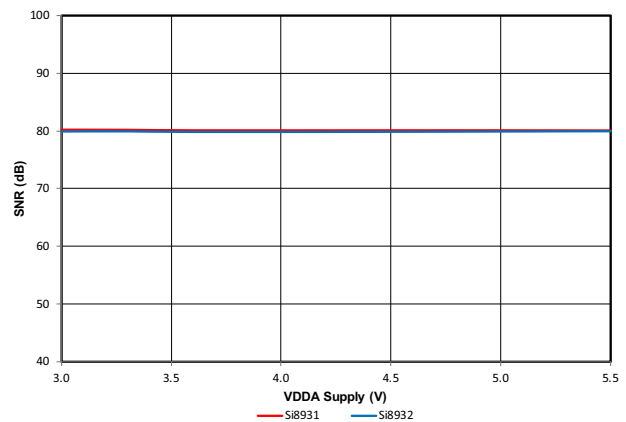


Figure 12. Signal-to-Noise Ratio (dB) vs. VDDA Supply (V)

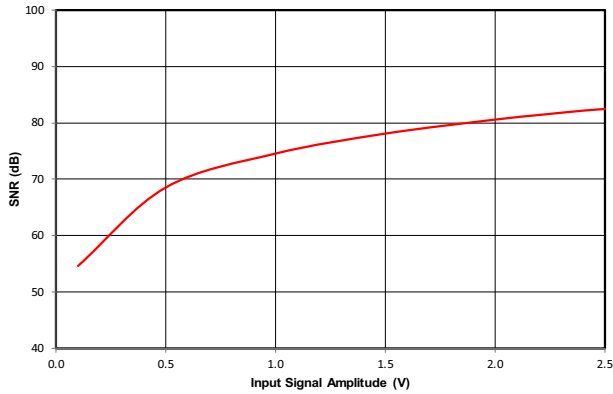


Figure 13. Si8931 Signal-to-Noise Ratio (dB) vs. Input Signal Amplitude (V)

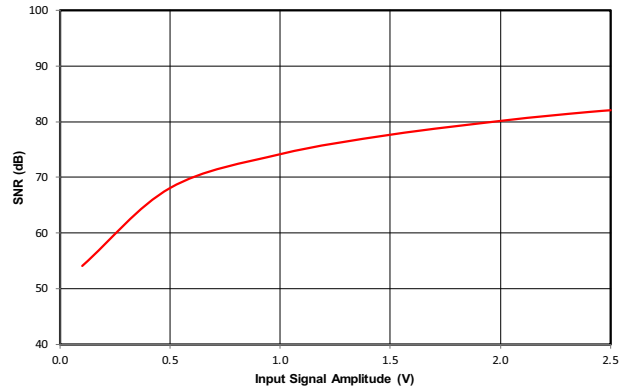


Figure 14. Si8932 Signal-to-Noise Ratio (dB) vs. Input Signal Amplitude (V)

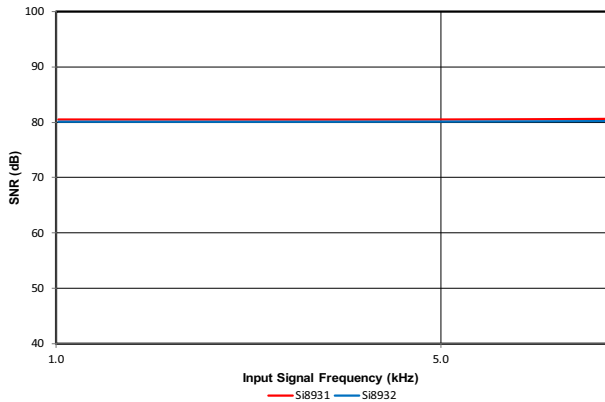


Figure 15. Signal-to-Noise Ratio (dB) vs. Input Signal Frequency (kHz)

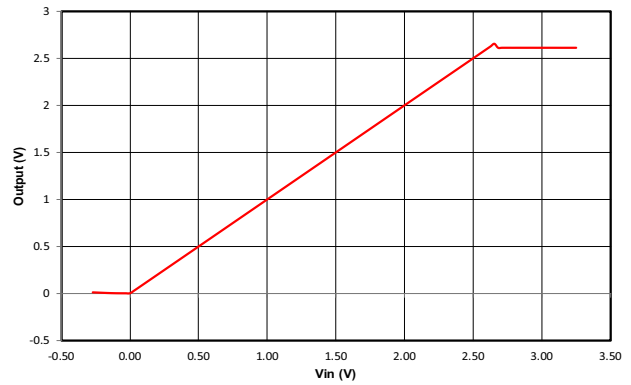


Figure 16. Output Voltage (V) vs. Input Voltage (V)

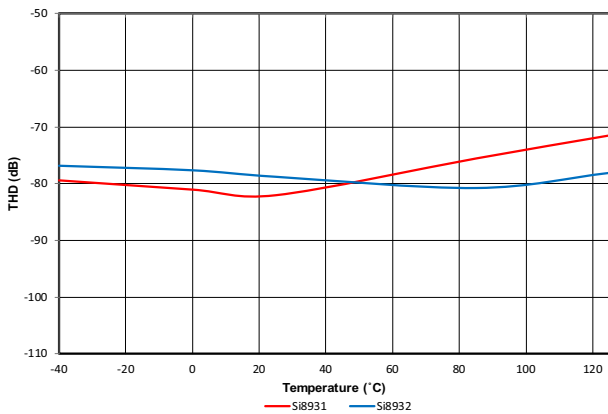


Figure 17. Total Harmonic Distortion (dB) vs. Temperature (°C)

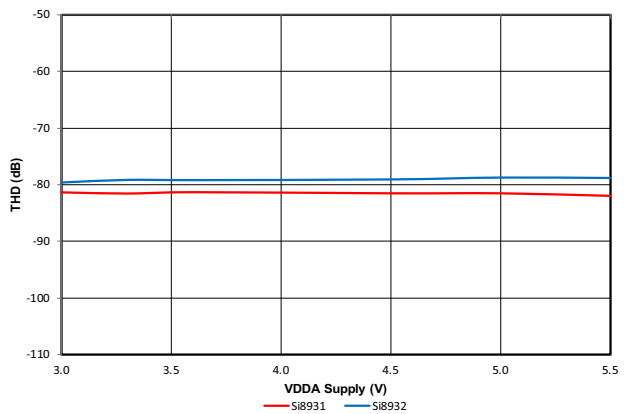


Figure 18. Total Harmonic Distortion (dB) vs. VDDA Supply (V)

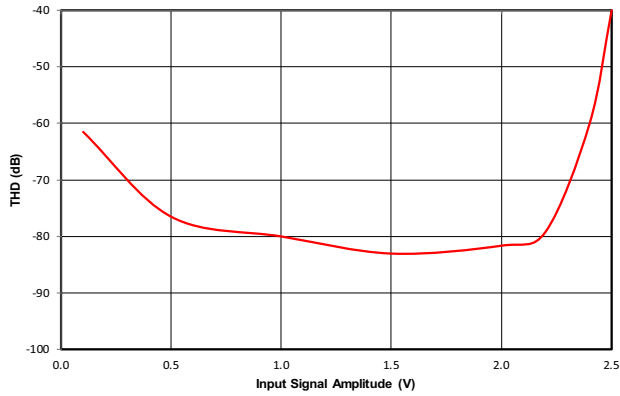


Figure 19. Si8931 Total Harmonic Distortion (dB) vs. Input Signal Amplitude (V)

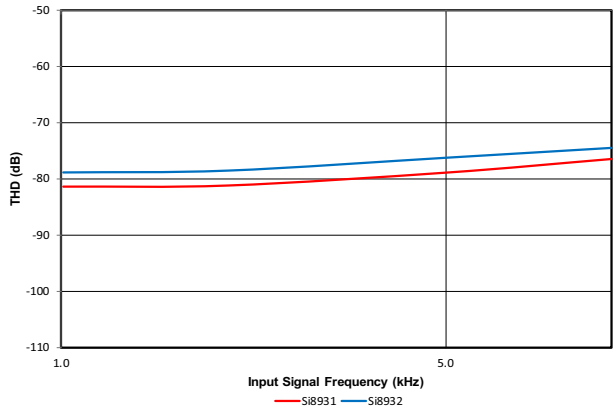


Figure 20. Total Harmonic Distortion (dB) vs. Input Signal Frequency (kHz)

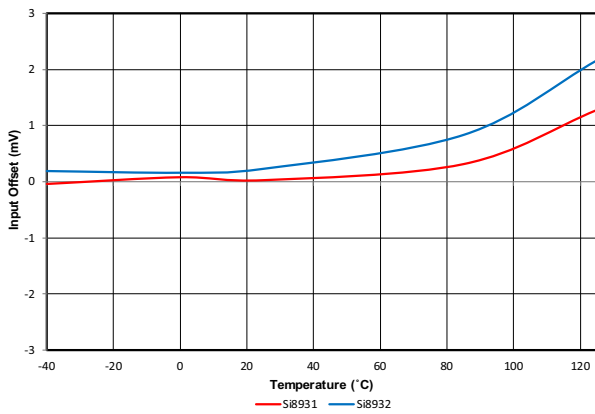


Figure 21. Input Offset (mV) vs. Temperature (°C)

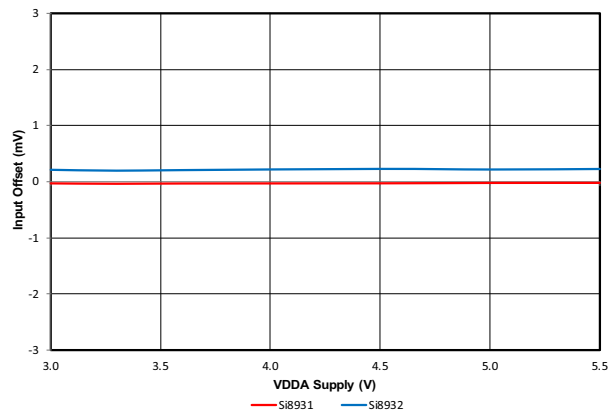


Figure 22. Input Offset (mV) vs. VDDA Supply (V)

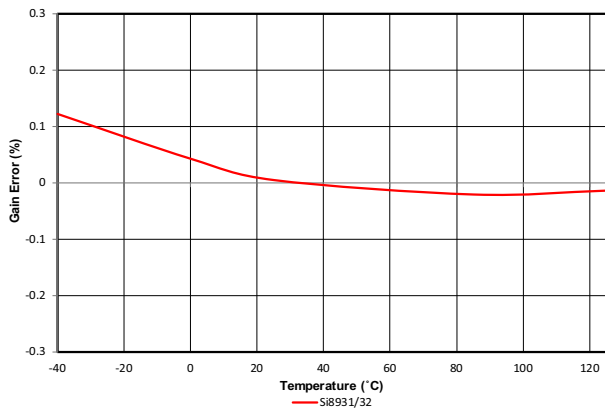


Figure 23. Gain Error (%) vs. Temperature (°C)

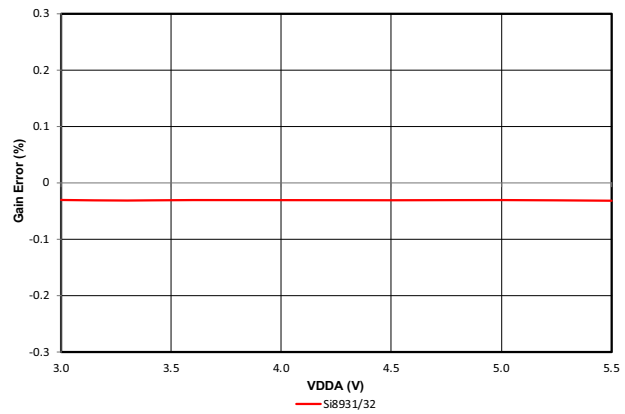


Figure 24. Gain Error (%) vs. VDDA Supply (V)

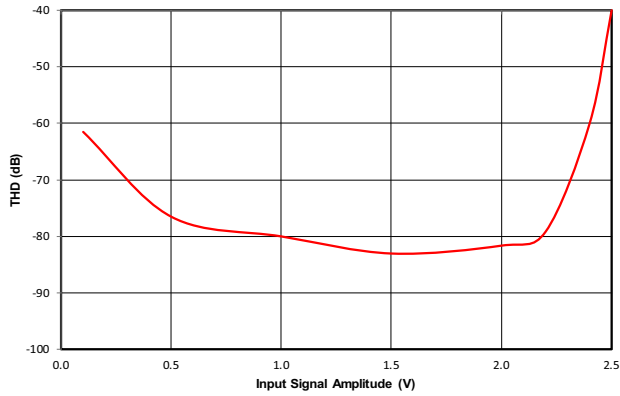


Figure 25. IDDA (mA) vs. Temperature (°C)

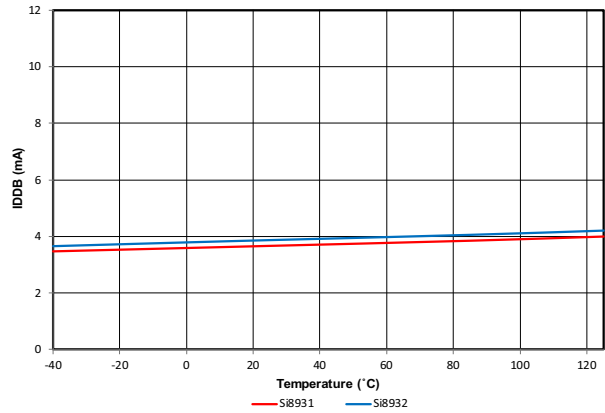


Figure 26. IDDB (mA) vs. Temperature (°C)

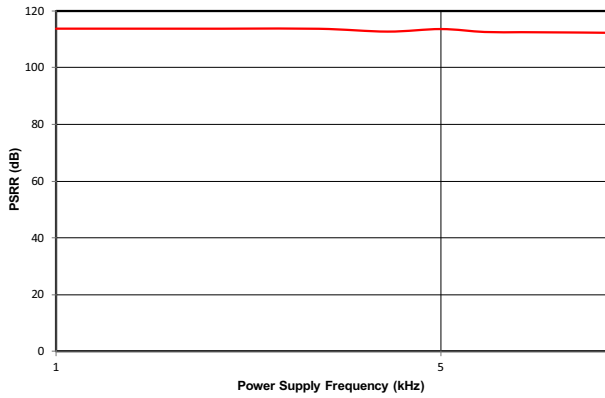


Figure 27. PSRR (dB) vs. Power Supply Frequency (kHz)

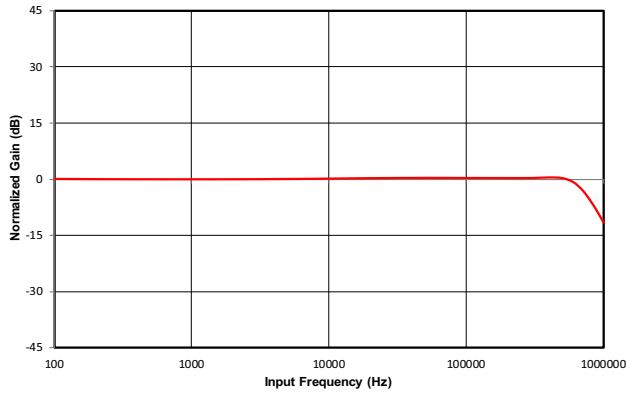


Figure 28. Amplifier Bandwidth

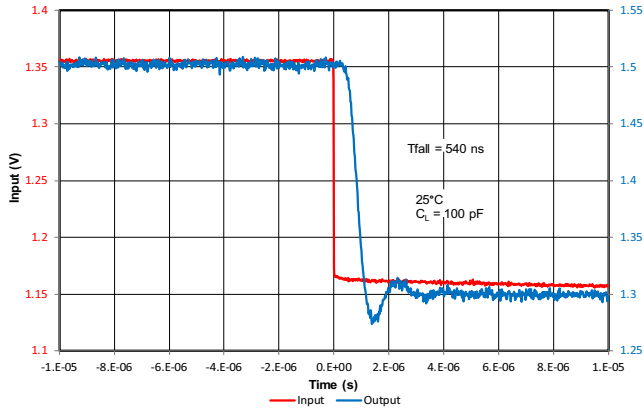


Figure 29. Si8931 High-to-Low Step Response

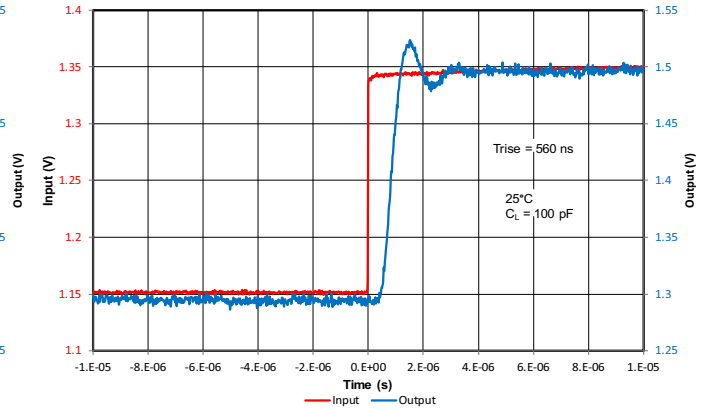


Figure 30. Si8931 Low-to-High Step Response

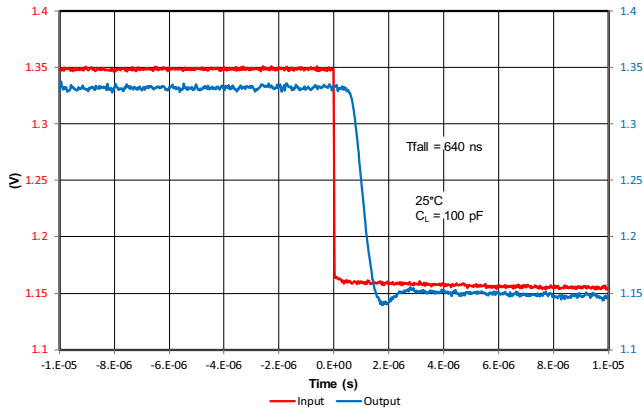


Figure 31. Si8932 High-to-Low Step Response

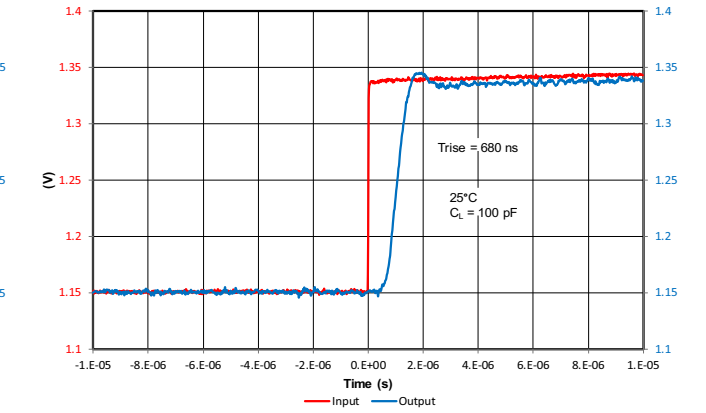


Figure 32. Si8932 Low-to-High Step Response

## 4. Safety Certifications and Specifications

**Table 6. Regulatory Information<sup>1</sup>**

<b>CSA</b>
The Si8931/Si8932 is certified under CSA. For more details, see Master Contract File 232873.
62368-1: Up to 600 V <sub>RMS</sub> reinforced insulation working voltage; up to 1000 V <sub>RMS</sub> basic insulation working voltage.
<b>VDE</b>
The Si8931/Si8932 is certified under VDE. For more details, see File 5028467.
60747-17: Up to 2121 V <sub>peak</sub> for reinforced insulation working voltage.
<b>UL</b>
The Si8931/Si8932 is certified under UL1577 component recognition program. For more details, see File E257455.
Rated up to 5000 V <sub>RMS</sub> V <sub>ISO</sub> isolation voltage for basic protection.
<b>CQC</b>
The Si8931/Si8932 is certified under GB4943.1.
Rated up to 250 V <sub>RMS</sub> reinforced insulation working voltage at 5000 meters tropical climate.

1. For more information, see Section 7. [Ordering Information](#)

**Table 7. Insulation and Safety-Related Specifications**

Parameter	Symbol	Test Condition	Value		Unit
			WB Stretched SOIC-8	NB SOIC-8	
Nominal external air gap (clearance)	CLR		8.0	4.0	mm
Nominal external tracking (creepage)	CRP		8.0	4.0	mm
Minimum internal gap (internal clearance)	DTI		0.036	0.036	mm
Tracking resistance	PTI or CTI	IEC60112	600	600	V <sub>RMS</sub>
Erosion depth	ED		0.04	0.04	mm
Resistance (input-output) <sup>1</sup>	R <sub>IO</sub>	Test voltage = 500 V, 25 °C	10 <sup>12</sup>	10 <sup>12</sup>	Ω
Capacitance (input-output) <sup>1</sup>	C <sub>IO</sub>	f = 1 MHz	1	1	pF

1. To determine resistance and capacitance, the Si8931/Si8932 is converted into a two-terminal device. Pins 1 to 4 are shorted together to form the first terminal, and pins 5 to 8 are shorted together to form the second terminal. The parameters are then measured between these two terminals.

Table 8. IEC 60664-1 Ratings

Parameter	Test Conditions	Specification	
		WB Stretched SOIC-8	NB SOIC-8
Material group		I	I
Overvoltage category	Rated mains voltage $\leq 150 V_{RMS}$	I-IV	I-IV
	Rated mains voltage $\leq 300 V_{RMS}$	I-IV	I-III
	Rated mains voltage $\leq 600 V_{RMS}$	I-IV	I-II
	Rated mains voltage $\leq 1000 V_{RMS}$	I-III	I

Table 9. IEC 60747-17 Insulation Characteristics<sup>1</sup>

Parameter	Symbol	Test Condition	Characteristic		Unit
			WB Stretched SOIC-8	NB SOIC-8	
Maximum working isolation voltage	$V_{IOWM}$	According to Time-Dependent Dielectric Breakdown (TDDB) Test	1500	445	$V_{RMS}$
Maximum repetitive isolation voltage	$V_{IORM}$	According to Time-Dependent Dielectric Breakdown (TDDB) Test	2121	630	$V_{peak}$
Apparent charge	$q_{pd}$	Method b: At routine test (100% production) and preconditioning (type test); $V_{ini} = 1.2 \times V_{IOTM}$ , $t_{ini} = 1$ s; $V_{pd(m)} = 1.875 \times V_{IORM}$ , $t_m = 1$ s (method b1) or $V_{pd(m)} = V_{ini}$ , $t_m = t_{ini}$ (method b2)	$\leq 5$	$\leq 5$	pC
Maximum transient isolation voltage	$V_{IOTM}$	$V_{TEST} = V_{IOTM}$ , $t = 60$ s (qualification); $V_{TEST} = 1.2 \times V_{IOTM}$ , $t = 1$ s (100% production)	7070	3535	$V_{peak}$
Maximum surge isolation voltage	$V_{IOSM}$	Tested in oil with $1.3 \times V_{IMP}$ or 10 kV minimum and $1.2 \mu s/50 \mu s$ profile	10400	10400	$V_{peak}$
Maximum impulse voltage	$V_{IMP}$	Tested in air with $1.2 \mu s/50 \mu s$ profile	8000	5000	$V_{peak}$
Isolation resistance	$R_{IO\_S}$	$T_{AMB} = T_S$ , $V_{IO} = 500$ V	$>10^9$	$>10^9$	$\Omega$
Pollution degree			2	2	
Climatic category			40/125/21	40/125/21	

1. This coupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

Table 10. UL 1577 Insulation Characteristics

Parameter	Symbol	Test Condition	Characteristic		Unit
			WB Stretched SOIC-8	NB SOIC-8	
Maximum withstanding isolation voltage	$V_{ISO}$	$V_{TEST} = V_{ISO}$ , $t = 60$ s (qualification); $V_{TEST} = 1.2 \times V_{ISO}$ , $t = 1$ s (100% production)	5000	2500	$V_{RMS}$

Table 11. IEC 60747-17 Safety Limiting Values<sup>1</sup>

Parameter	Symbol	Test Condition	Characteristic	Unit
Safety temperature	$T_S$		150	°C
Safety input, output or supply current (WB stretched SOIC-8)	$I_S$	$\theta_{JA} = 90\text{ °C/W}$ $V_{DD} = 5.5\text{ V}$ $T_J = 150\text{ °C}$ $T_A = 25\text{ °C}$	253	mA
		$\theta_{JA} = 90\text{ °C/W}$ $V_{DD} = 3.6\text{ V}$ $T_J = 150\text{ °C}$ $T_A = 25\text{ °C}$	386	mA
Safety input, output or supply current (NB SOIC-8)	$I_S$	$\theta_{JA} = 112\text{ °C/W}$ $V_{DD} = 5.5\text{ V}$ $T_J = 150\text{ °C}$ $T_A = 25\text{ °C}$	203	mA
		$\theta_{JA} = 112\text{ °C/W}$ $V_{DD} = 3.6\text{ V}$ $T_J = 150\text{ °C}$ $T_A = 25\text{ °C}$	310	mA
Safety input, output or total power (WB stretched SOIC-8)	$P_S$	$\theta_{JA} = 90\text{ °C/W}$ $T_J = 150\text{ °C}$ $T_A = 25\text{ °C}$	1389	mW
Safety input, output or total power (NB SOIC-8)	$P_S$	$\theta_{JA} = 112\text{ °C/W}$ $T_J = 150\text{ °C}$ $T_A = 25\text{ °C}$	1116	mW

1. Maximum value allowed in the event of a failure. Refer to the derating curves Figure 33, “WB Stretched SOIC-8 Thermal Derating Curve (Dependence of Safety Limiting Current),” on page 16 and Figure 34, “NB SOIC-8 Thermal Derating Curve (Dependence of Safety Limiting Current),” on page 17.

Table 12: Thermal Characteristics

Parameter	Symbol	WB Stretched SOIC-8	NB SOIC-8	Unit
IC Junction-to-air thermal resistance	$\theta_{JA}$	90	112	°C/W

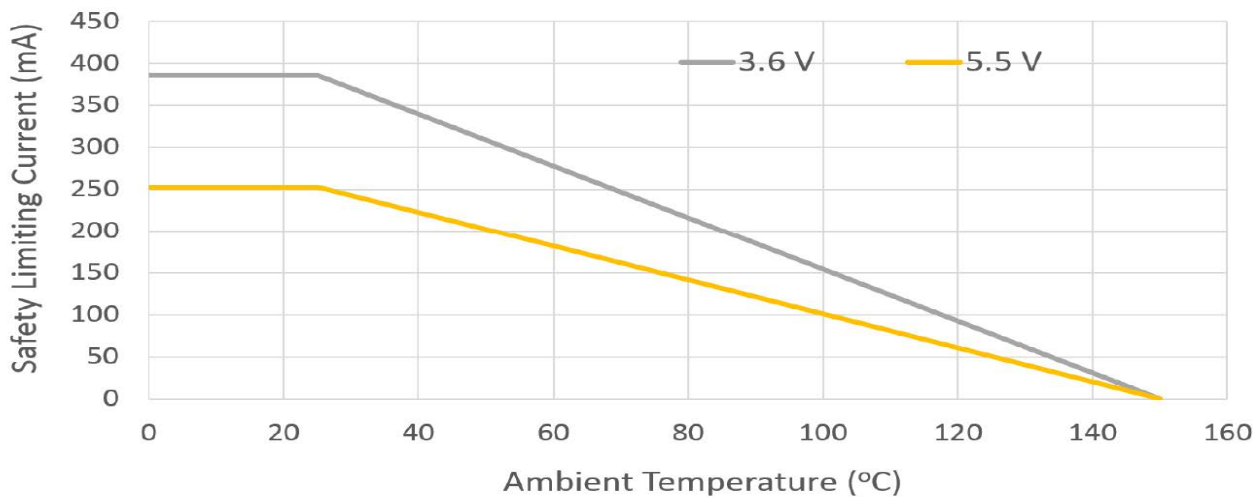


Figure 33. WB Stretched SOIC-8 Thermal Derating Curve (Dependence of Safety Limiting Current)

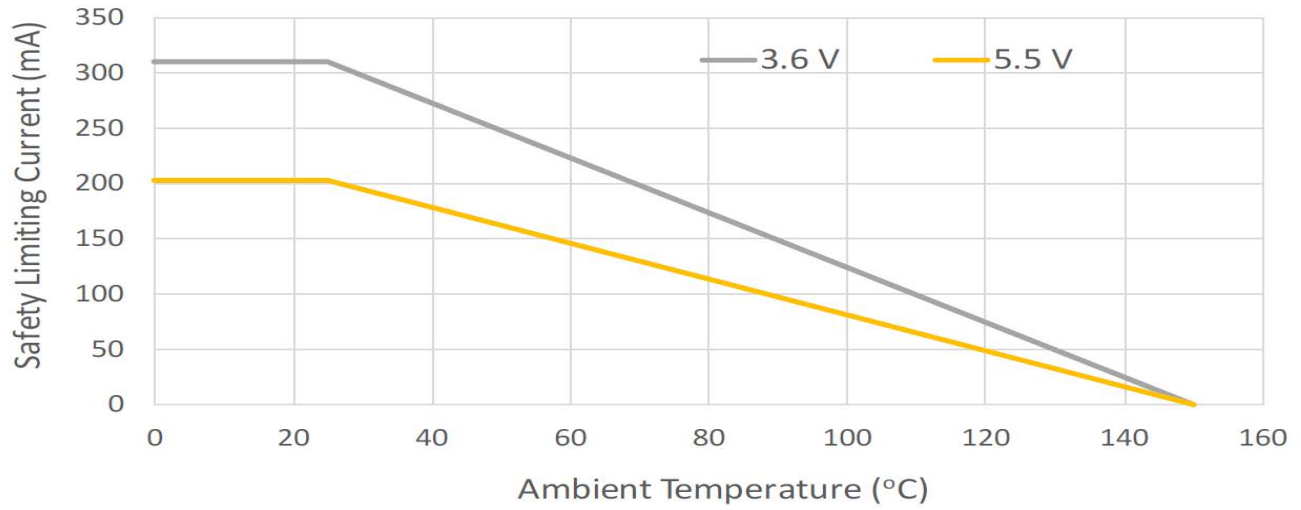


Figure 34. NB SOIC-8 Thermal Derating Curve (Dependence of Safety Limiting Current)

## 5. Package and Handling Information

Since the device package is sensitive to moisture absorption, it is baked and vacuum packed before shipping. Instructions on the shipping container label regarding exposure to moisture after the container seal is broken must be followed. Otherwise, problems related to moisture absorption may occur when the part is subjected to high temperature during solder assembly.

The Si8931D-IS4, Si8931D-AS4, Si8932D-IS4, and Si8932D-AS4 are rated to Moisture Sensitivity Level 2A (MSL2A) at 260°C, while the Si8931B-IS, Si8931B-AS, Si8932B-IS, and Si8932B-AS are rated to MSL2 at 260°C.

They can be used for lead or lead-free soldering. For additional information, refer to Skyworks Application Note, "PCB Design and SMT Assembly/Rework Guidelines," Document Number 101752.

Care must be taken when attaching this product, whether it is done manually or in a production solder reflow environment. Refer to Standard SMT Reflow Profiles: JEDEC Standard J-STD-020.

5.1. Package Outline: 8-Pin Wide Body Stretched SOIC

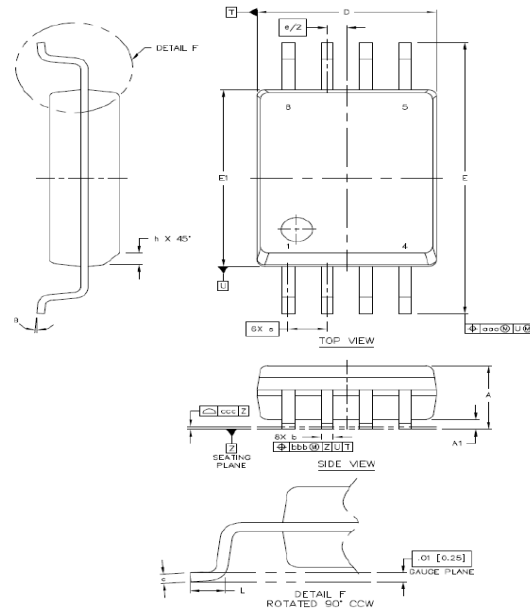


Figure 35. 8-Pin Wide Body Stretched SOIC Package

Table 13. 8-Pin Wide Body Stretched SOIC Package Dimensions

Dimension	Millimeters		Notes
	Min	Max	
A	2.49	2.79	Dimensioning and tolerancing per ANSI Y14.5M-1994. Recommended reflow profile per JEDEC J-STD-020C specification for small body, lead-free components.
A1	0.36	0.46	
b	0.30	0.51	
c	0.20	0.33	
D	5.74	5.94	
E	11.25	11.76	
E1	7.39	7.59	
e	1.27 BSC		
L	0.51	1.02	
h	0.25	0.76	
θ	0°	8°	
aaa		0.25	
bbb		0.25	
ccc		0.10	

## 6. Land Pattern: 8-Pin Wide Body Stretched SOIC

### 6.0.1. General Guidelines

1. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a fabrication allowance of 0.05 mm.
2. This land pattern design is based on the IPC-7351 guidelines.

### 6.0.2. Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD).
2. Clearance between the solder mask and the metal pad is to be 60  $\mu\text{m}$  minimum, all the way around the pad.

### 6.0.3. Stencil Design

1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pins.

### 6.0.4. Card Assembly

1. A No-clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

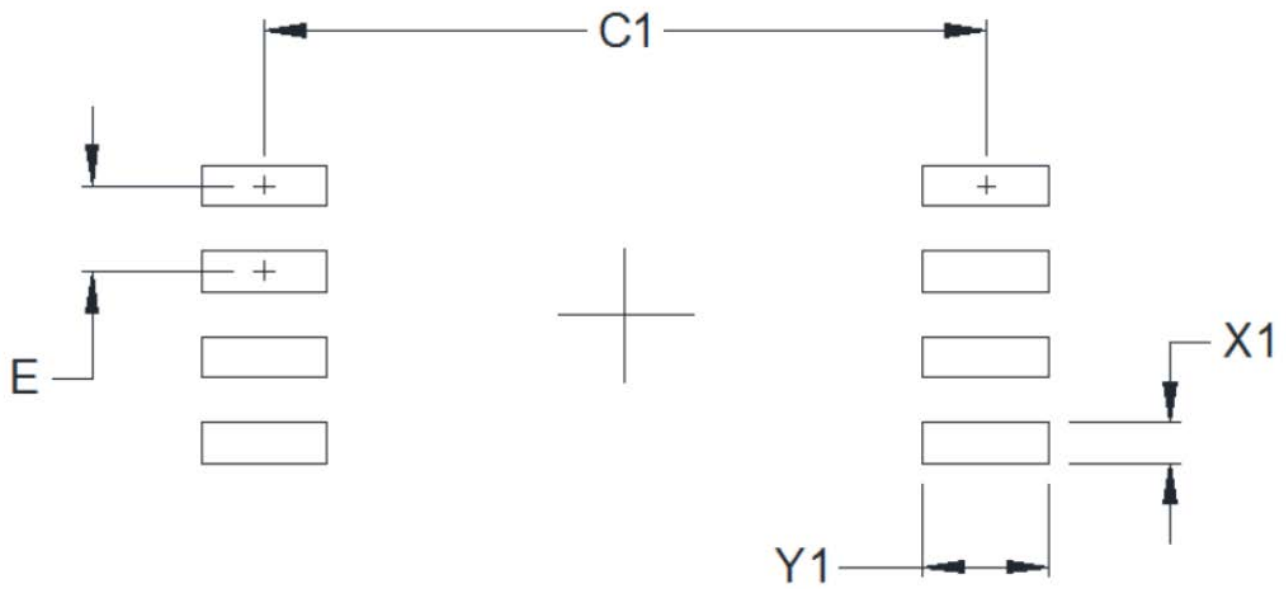


Figure 36. 8-Pin Wide Body Stretched SOIC Land Pattern

Table 14. 8-Pin Wide Body Stretched SOIC Land Pattern Dimensions<sup>1</sup>

Dimension	(mm)
C1	10.60
E	1.27
X1	0.60
Y1	1.85

1. See General Guidelines

6.1. Package Marking: 8-Pin Wide Body Stretched SOIC

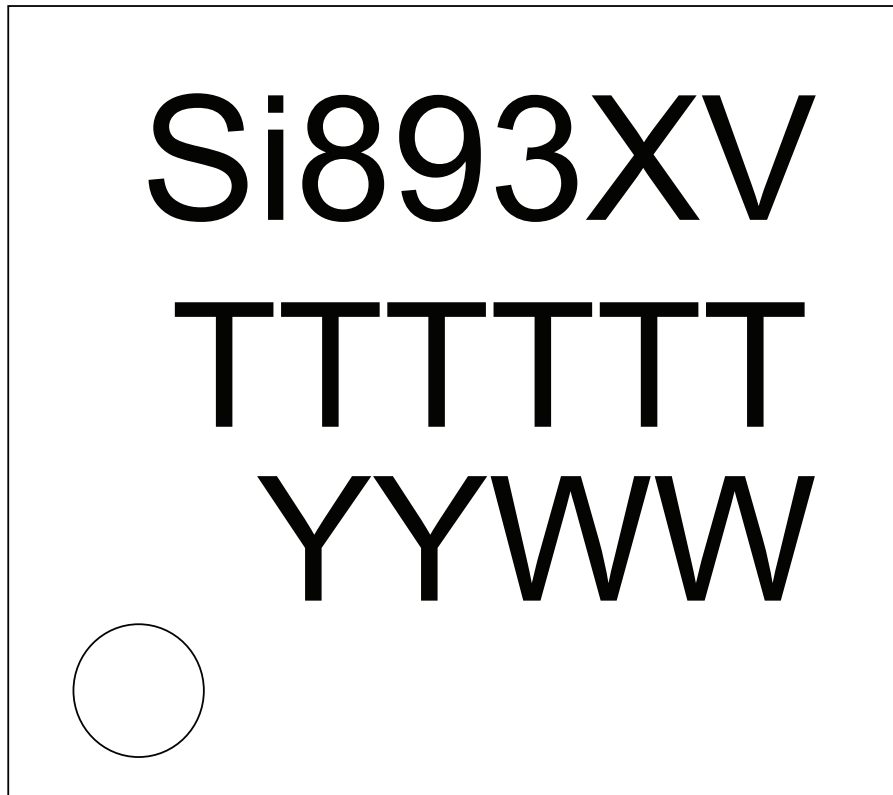
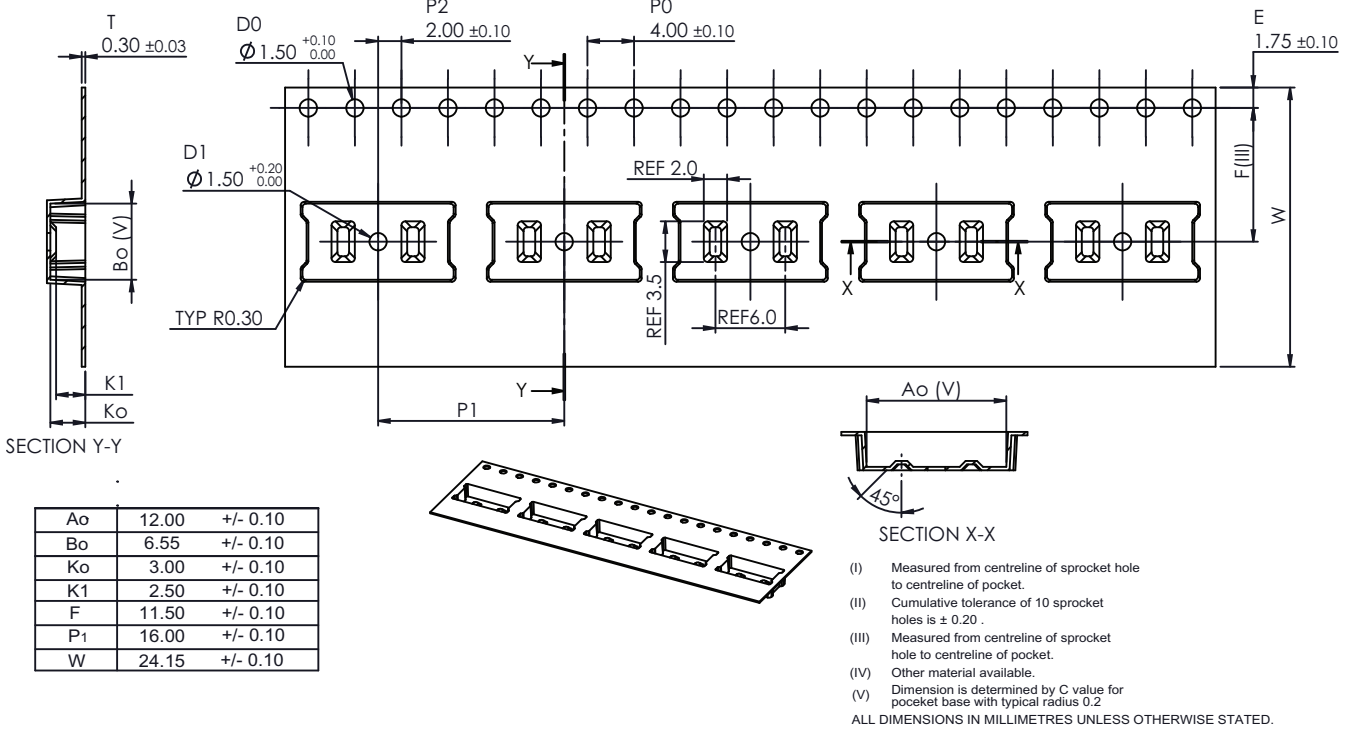


Figure 37. Si8931/32 Typical Package Marking, 8-Pin Wide Body Stretched SOIC

Table 15: 8-Pin Wide Body Stretched SOIC Marking Explanation

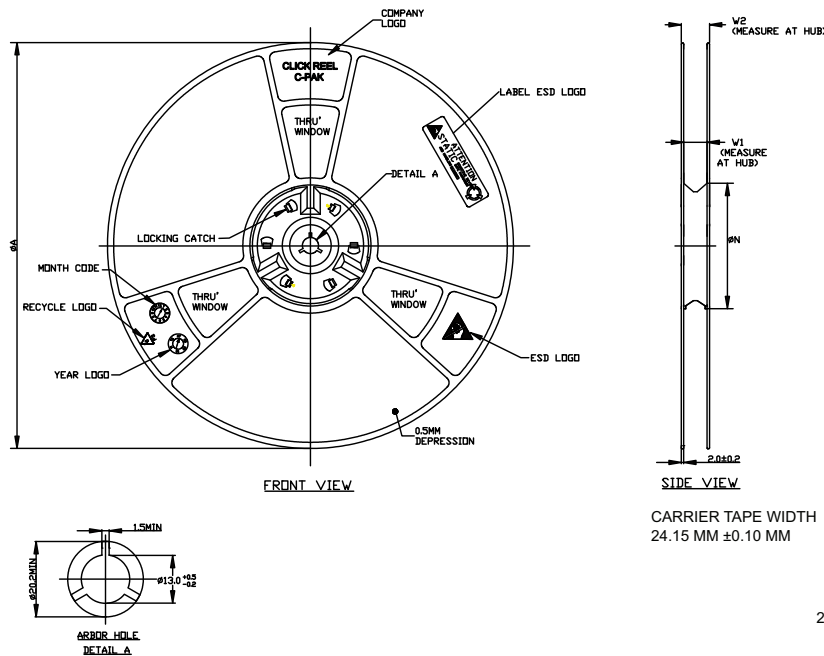
Line 1	Part Number	Si893x X = Base part number 1 = Differential output 2 = Single-ended output  V = Insulation rating: D = 5.0 kV <sub>RMS</sub>
Line 2	TTTTTT	Manufacturing Code
Line 3	YY = Year WW = Work Week Circle = 43 mils diameter left justified	Year and work week

6.2. Tape and Reel Information: 8-Pin Wide Body Stretched SOIC



206438-041

Figure 38. Wide Body Carrier Tape Information



206438-042

Figure 39. Wide Body Reel Information

6.3. Package Outline: 8-Pin Narrow Body SOIC

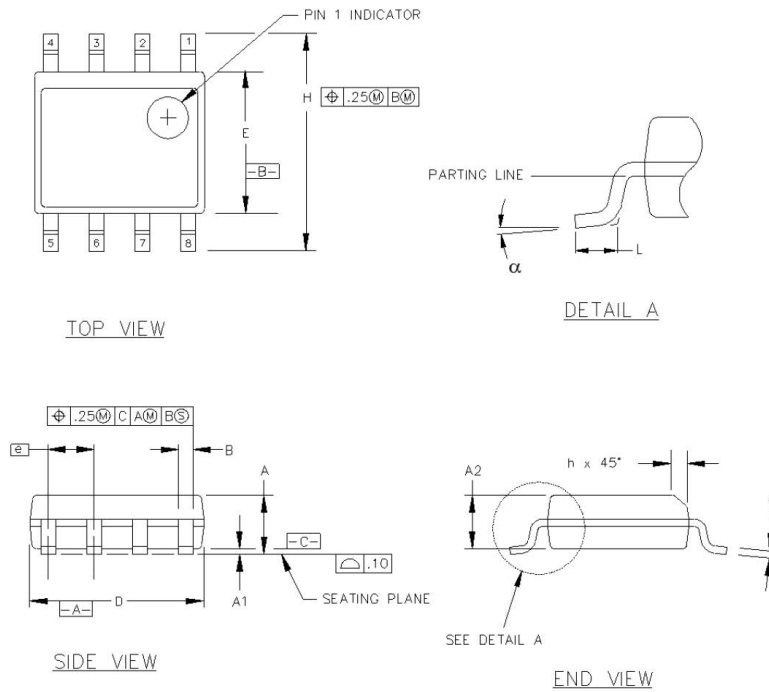


Figure 40. 8-Pin Narrow Body SOIC Package

Table 16. 8-Pin Narrow Body SOIC Package Dimensions

Dimension	Millimeters		Notes
	Min	Max	
A	1.35	1.75	Dimensioning and tolerancing per ANSI Y14.5M-1982.  This drawing conforms to JEDEC Outline MS-012.  Recommended card reflow profile is per the JEDEC/IPC J-STD-020B specification for small body components.
A1	0.10	0.25	
A2	1.40 REF	1.55 REF	
B	0.33	0.51	
C	0.19	0.25	
D	4.80	5.00	
E	3.80	4.00	
e	1.27 BSC		
H	5.80	6.20	
h	0.25	0.50	
L	0.40	1.27	
$\alpha$	0°	8°	

### 6.4. Land Pattern: 8-Pin Narrow Body SOIC

#### General Guidelines

1. All feature sizes shown are at Maximum Material Condition (MMC) and a card fabrication tolerance of 0.05 mm is assumed.
2. This Land Pattern Design is based on IPC-7351 pattern SOIC127P600X173-8N for Density Level B (Median Land Protrusion).

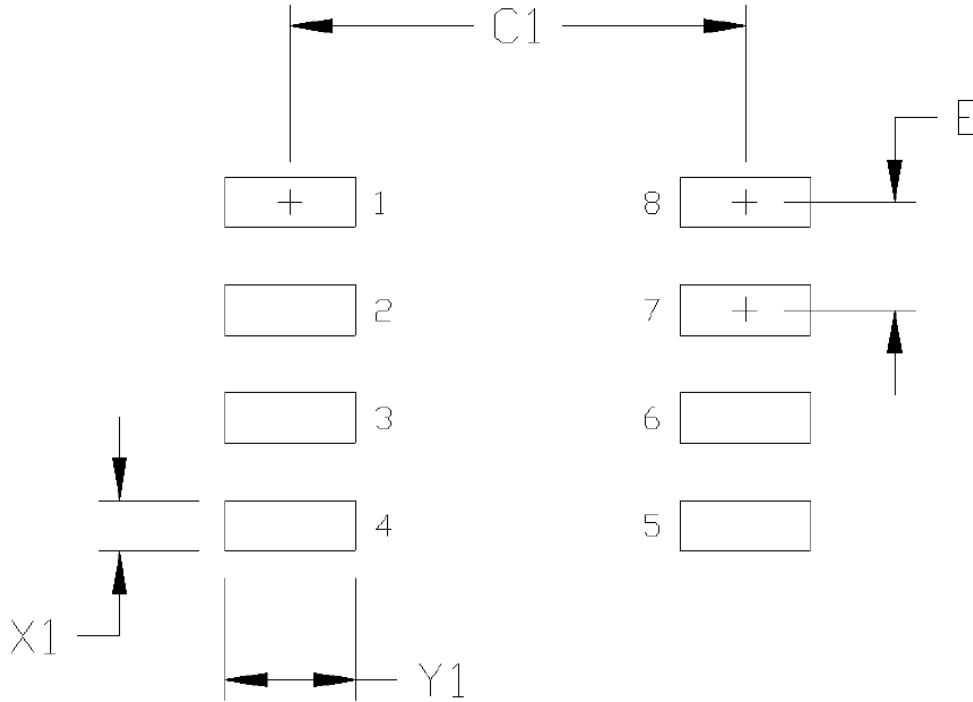


Figure 41. 8-Pin Narrow Body SOIC Land Pattern

Table 17. 8-Pin Narrow Body SOIC Land Pattern Dimensions<sup>1</sup>

Dimension	mm
C1	5.40
E	1.27
X1	0.60
Y1	1.55

1. See General Guidelines

6.5. Package Marking: 8-Pin Narrow Body SOIC

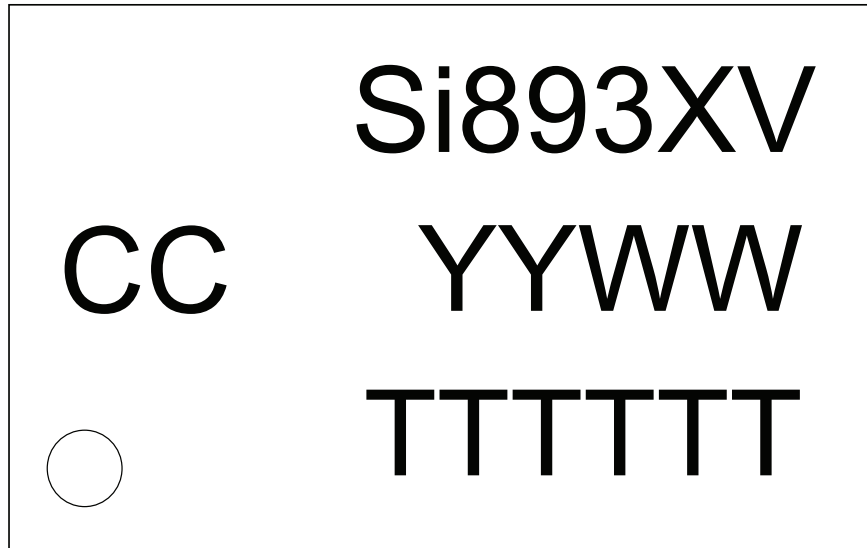


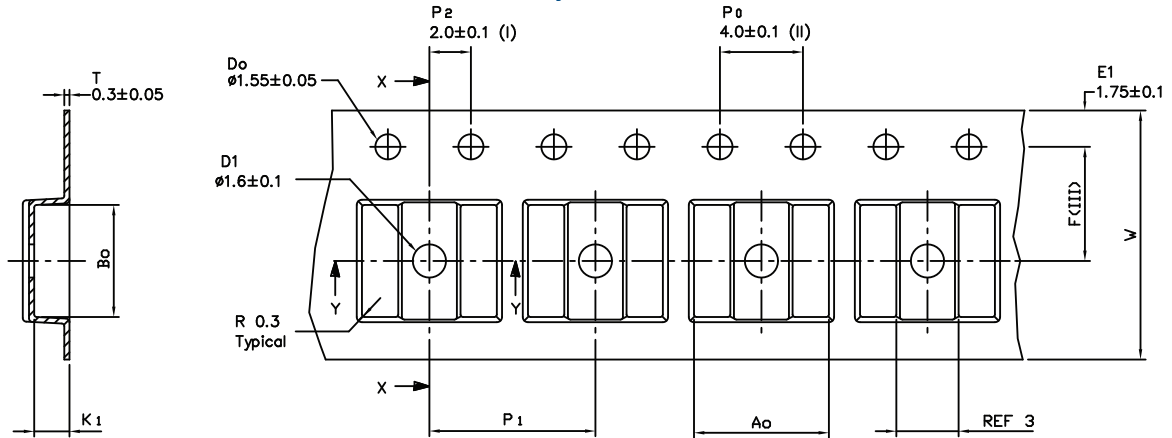
Figure 42. Si8931/32 Typical Package Marking, 8-Pin Narrow Body SOIC

Table 18. 8-Pin Narrow Body SOIC Marking Explanation

Line 1	Part Number	Si893x X = Base part number 1 = Differential output 2 = Single-ended output  V = Insulation rating B = 2.5 kV <sub>RMS</sub>
Line 2	CC = Country of origin ISO code abbreviation	
	YY = Year WW = Work Week	Year and work week
Line 3	Circle = 19.7 mils diameter left justified	Manufacturing code

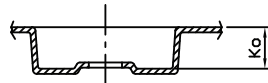
Figure 43.

6.6. Tape and Reel Information: 8-Pin Narrow Body SOIC



SECTION X - X

Ao	6.50 +/- 0.1
Bo	5.40 +/- 0.1
Ko	2.00 +/- 0.1
K1	1.70 +/- 0.1
F	5.50 +/- 0.1
P1	8.00 +/- 0.1
W	12.00 +0.3/-0.0



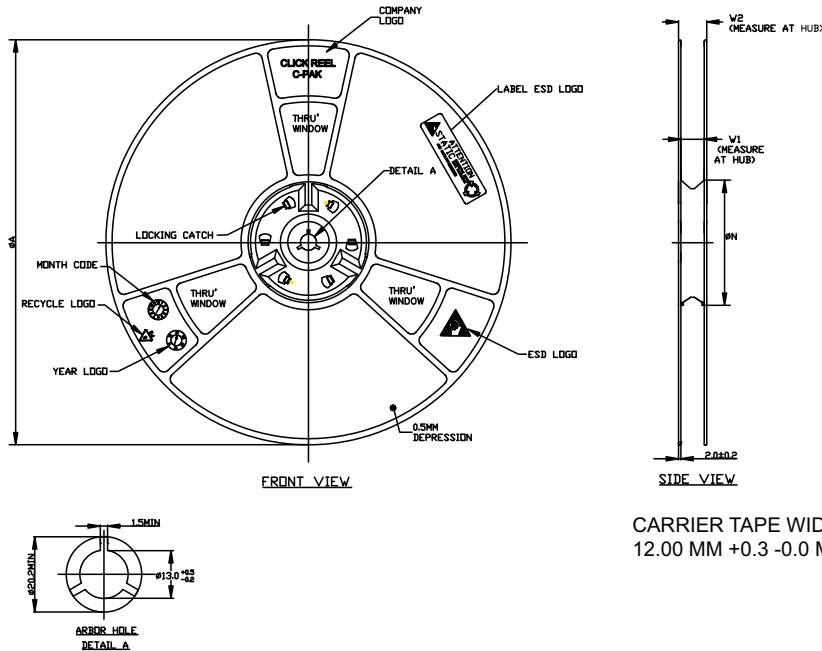
SECTION Y - Y

- (I) Measured from centreline of sprocket hole to centreline of pocket.
- (II) Cumulative tolerance of 10 sprocket holes is ± 0.20 .
- (III) Measured from centreline of sprocket hole to centreline of pocket.
- (IV) Other material available.

ALL DIMENSIONS IN MILLIMETRES UNLESS OTHERWISE STATED.

206438-043

Figure 44. Narrow Body Carrier Tape Information



206438-044

Figure 45. Narrow Body Reel Information

## 7. Ordering Information

### 7.1. Industrial and Automotive Grade Ordering Part Numbers (OPNs)

Industrial-grade devices (part numbers with an “-I” in their suffix) are built using well-controlled, high-quality manufacturing flows to ensure robustness and reliability. Qualifications are compliant with JEDEC, and defect reduction methodologies are used throughout definition, design, evaluation, qualification, and mass production steps.

Automotive-grade devices (part numbers with an “-A” in their suffix) are built using automotive-specific flows at all steps in the manufacturing process to ensure robustness and low defectivity. These devices are supported with AIAG-compliant Production Part Approval Process (PPAP) documentation, and feature International Material Data System (IMDS) and China Automotive Material Data System (CAMDS) listings. Qualifications are compliant with AEC-Q100, and a zero-defect methodology is maintained throughout definition, design, evaluation, qualification, and mass production steps.

Ordering Part Number <sup>1, 2, 3</sup>	Automotive Ordering Part Number <sup>1, 2, 3, 4, 5</sup>	Ordering Options			
		Input Range	Isolation Rating	Output	Package Type
Si8931D-IS4	Si8931D-AS4	0 to 2.5 V nominal	5.0 kV <sub>RMS</sub>	Differential	WB stretched SOIC-8
Si8931B-IS	Si8931B-AS	0 to 2.5 V nominal	2.5 kV <sub>RMS</sub>	Differential	NB SOIC-8
Si8932D-IS4	Si8932D-AS4	0 to 2.5 V nominal	5.0 kV <sub>RMS</sub>	Single-ended	WB stretched SOIC-8
Si8932B-IS	Si8932B-AS	0 to 2.5 V nominal	2.5 kV <sub>RMS</sub>	Single-ended	NB SOIC-8

1. All packages are RoHS-compliant.
2. “Si” and “SI” are used interchangeably.
3. An “R” at the end of the part number denotes tape and reel packaging option.
4. Automotive-grade devices (“-A” suffix) are identical in construction materials, topside marking, and electrical parameters to their Industrial Grade (“-I suffix”) version counterparts. Automotive-Grade products are produced utilizing full automotive process flows and additional statistical process controls throughout the manufacturing flow. The Automotive-Grade part number is included on shipping labels.
5. In the top markings of each device, the Manufacturing Code represented by “TTTTTT” contains as its first character a letter in the range N through Z to indicate Automotive Grade.

## 8. Revision History

### Revision D

**October 2, 2023**

Updated regulatory information, updated note 1 of absolute maximum table, removed not needed minimum IDD specification, and added back in timing specifications that were inadvertently removed on the previous revision.

### Revision C

May, 2023

Updated block diagrams on page 1, Si8932 pin description, and regulatory information.

### Revision B

February, 2023

Re-formatted to new standards. Added new text for Automotive Grade products, AEC-Q100 qualification, added tape and reel information, added MSL ratings. Updated THD specifications.

### Revision 206438A

December, 2022

Updated decimal-based revision number to alphanumeric code.

### Revision 0.9

September, 2022

Updated Safety Approvals on front page.

Updated minimum supply currents in 4. Electrical Specifications.

Updated 4.1 Regulatory Information.

### Revision 0.8

May, 2021

Added Automotive OPNs to Ordering Guide

Updated Figure 3.1 Voltage Sense Application on page 6.

Updated Table 4.4 Absolute Maximum Ratings 1 on page 11.

Added Surge Voltage parameter to Table 4.8 IEC 60747-17 Insulation Characteristics 1 on page 13.

Changed "60 mm" to "60 μm" in Solder Mask Design note in Table 6.3 8-Pin Wide Body Stretched SOIC Land Pattern Dimensions on page 25.

### Revision 0.7

December, 2019

Updated Applications and Key Features on front page.

Updated Electrical Specifications after full characterization.

Added section for Automotive Grade OPNs.

Updated Table 4.6 Insulation and Safety-Related Specifications on page 12.

Updated 6.6 Top Marking: 8-Pin Narrow Body SOIC.

Changed Si8932 Pin 6 from NC to GND.

Numerous clarifications throughout.

**Revision 0.5**

March, 2019

Updated specifications.

Added narrow body SOIC-8 package.

**Revision 0.2**

May, 2018

Corrections and clarifications.

**Revision 0.1**

January, 2018

Initial draft.

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